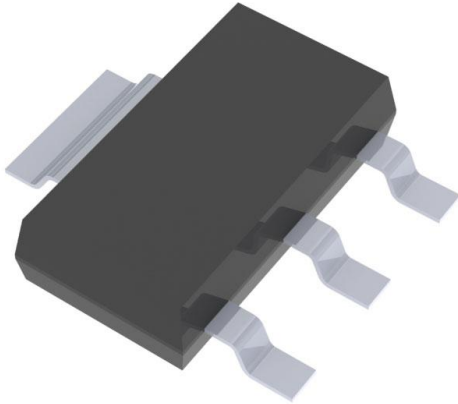


BSP75NQTA Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	BSP75NQTA-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	BSP75NQTA
Description	IC PWR SWITCH N-CHAN 1:1 SOT223
Detailed Description	Power Switch/Driver 1:1 N-Channel 1.3A SOT-223



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

BSP75NQTA

Series:

-

Switch Type:

General Purpose

Ratio - Input:Output:

1:1

Output Type:

N-Channel

Voltage - Load:

60V (Max)

Current - Output (Max):

1.3A

Input Type:

Non-Inverting

Fault Protection:

Current Limiting (Fixed), Over Temperature, Over Voltage

Grade:

Automotive

Mounting Type:

Surface Mount

Package / Case:

TO-261-4, TO-261AA

Manufacturer:

Diodes Incorporated

Product Status:

Active

Number of Outputs:

1

Output Configuration:

Low Side

Interface:

On/Off

Voltage - Supply (Vcc/Vdd):

Not Required

Rds On (Typ):

385mOhm

Features:

Auto Restart

Operating Temperature:

-40°C ~ 150°C (TJ)

Qualification:

AEC-Q101

Supplier Device Package:

SOT-223

Base Product Number:

BSP75

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8542.39.0001

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99


BSP75NQ
60V SELF-PROTECTED LOW-SIDE IntelliFET MOSFET SWITCH

Product Summary

- Continuous Drain-Source Voltage: $V_{DS} = 60V$
- On-State Resistance: $500m\Omega$
- Max Nominal Load Current ($V_{IN} = 5V$): 1.1A
- Min Nominal Load Current ($V_{IN} = 5V$): 0.7A
- Clamping Energy: 550mJ

Description

The BSP75NQ is a self-protected low-side IntelliFET[®] MOSFET. It features monolithic overtemperature, overcurrent, overvoltage (active clamp) and ESD protected logic-level functionality. It is intended as a general-purpose switch.

Applications

- Especially suited for loads with a high inrush current such as lamps and motors
- All types of resistive, inductive and capacitive loads in switching applications
- μC compatible power switches for 12V and 24V DC applications
- Automotive rated
- Replaces electromechanical relays and discrete circuits
- Linear mode capabilities - the current-limiting protection circuitry is designed to de-activate at low V_{DS} in order not to compromise the load current during normal operation. The maximum DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry. This does not compromise the product's ability to self-protect at low V_{DS} .

Features and Benefits

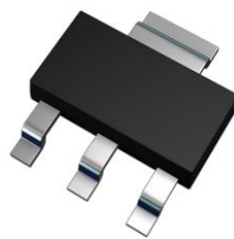
- Short-Circuit Protection with Auto Restart
- Overvoltage Protection (Active Clamp)
- Thermal Shutdown with Auto Restart
- Overcurrent Protection
- Input Protection (ESD)
- Load Dump Protection (Actively Protects Load)
- Logic-Level Input
- High Continuous Current Rating
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The BSP75NQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

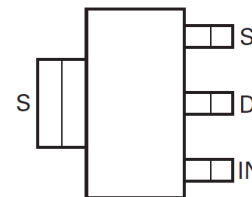
Mechanical Data

- Package: SOT223
- Package Material: Molded Plastic, "Green" Molding Compound
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish e3
- Weight: 0.112 grams (Approximate)

SOT223 (Type DN)



Top View



Top View
Pinout

Note: The tab is connected to the source pin and must be electrically isolated from the drain pin. Connection of significant copper to the drain pin is recommended for best thermal performance.

Ordering Information (Note 4)

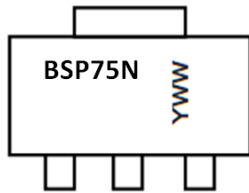
Orderable Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
BSP75NQTA	SOT223 (Type DN)	BSP75N	7	12	1,000 Units	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.



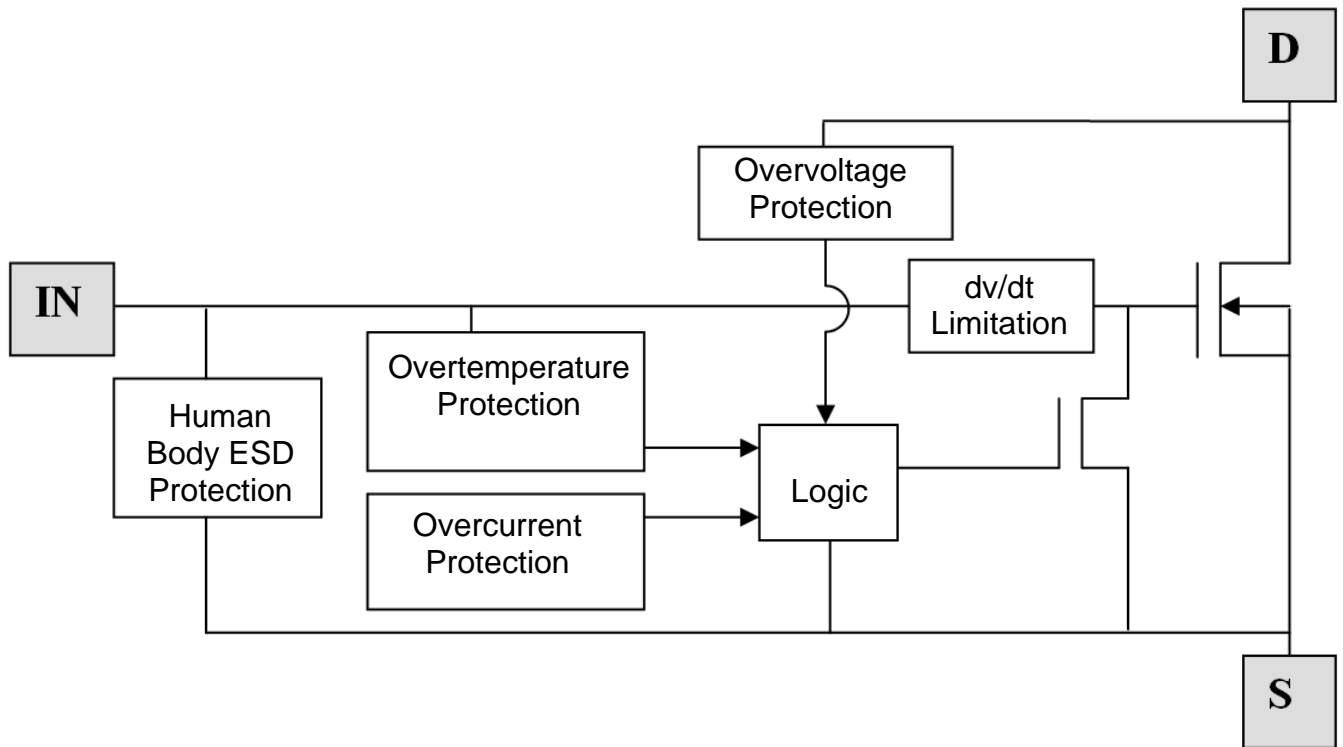
BSP75NQ

Marking Information



BSP75N = Product Type Marking Code
 YWW = Date Code Marking
 Y or \bar{Y} = Last Digit of Year (ex: 4 = 2024)
 WW or \bar{W} = Week Code (01 to 53)

Functional Block Diagram





BSP75NQ

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Value	Unit
Continuous Drain-Source Voltage	V _{DS}	60	V
Drain-Source Voltage for Short-Circuit Protection V _{IN} = 5V	V _{DS(SC)}	36	V
Drain-Source Voltage for Short-Circuit Protection V _{IN} = 10V	V _{DS(SC)}	20	V
Continuous Input Voltage	V _{IN}	-0.2 to 10	V
Peak Input Voltage	V _{IN}	-0.2 to 20	V
Operating Temperature Range	T _J	-40 to +150	°C
Storage Temperature Range	T _{STG}	-55 to +150	°C
Power Dissipation at T _A = +25°C (Note 5)	P _D	1.5	W
Power Dissipation at T _A = +25°C (Note 6)	P _D	0.6	W
Continuous Drain Current @ V _{IN} = 10V; T _A = +25°C (Note 5)	I _D	1.3	A
Continuous Drain Current @ V _{IN} = 5V; T _A = +25°C (Note 5)	I _D	1.1	A
Continuous Drain Current @ V _{IN} = 5V; T _A = +25°C (Note 6)	I _D	0.7	A
Continuous Source Current (Body Diode) (Note 5)	I _S	2.0	A
Pulsed Source Current (Body Diode) (Note 7)	I _S	3.3	A
Unclamped Single Pulse Inductive Energy	E _{AS}	550	mJ
Load Dump Protection	V _{LOAD_DUMP}	80	V
Electrostatic Discharge (Human Body Model)	V _{ESD}	4000	V
DIN Humidity Category, DIN 40 040	—	E	—
IEC Climatic Category, DIN IEC 68-1	—	40/150/56	—

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction to Ambient (Note 5)	R _{θJA}	83	°C/W
Junction to Ambient (Note 7)	R _{θJA}	45	°C/W
Junction to Ambient (Note 6)	R _{θJA}	208	°C/W

- Notes:
5. For a device surface-mounted on 25mm x 25mm x 1.6mm FR-4 board with a high coverage of single sided 2oz weight copper. Allocation of 6cm² copper 33% to source tab and 66% to drain pin with source tab and drain pin electrically isolated.
 6. For a device surface-mounted on FR-4 board with the minimum copper required for electrical connections.
 7. For a device surface-mounted on FR-4 board as (a) and measured at t ≤ 10s.



BSP75NQ

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Conditions
Static Characteristics						
Drain-Source Clamp Voltage	V _{DS(AZ)}	60	70	75	V	I _D = 10mA
Off-State Drain Current	I _{DSS}	—	0.1	3	μA	V _{DS} = 12V, V _{IN} = 0V
Off-State Drain Current	I _{DSS}	—	3	15	μA	V _{DS} = 32V, V _{IN} = 0V
Input Threshold Voltage (Note 8)	V _{IN(TH)}	1	2.1	—	V	V _{DS} = V _{GS} , I _D = 1mA
Input Current	I _{IN}	—	0.7	1.2	mA	V _{IN} = 5V
Input Current	I _{IN}	—	1.5	2.7	mA	V _{IN} = 7V
Input Current	I _{IN}	—	4	7	mA	V _{IN} = 10V
Static Drain-Source On-State Resistance	R _{DS(ON)}	—	520	675	mΩ	V _{IN} = 5V, I _D = 0.7A
Static Drain-Source On-State Resistance	R _{DS(ON)}	—	385	550	mΩ	V _{IN} = 10V, I _D = 0.7A
Current Limit (Note 9)	I _{D(LIM)}	0.7	1.0	1.5	A	V _{IN} = 5V, V _{DS} > 5V
Current Limit (Note 9)	I _{D(LIM)}	1	1.8	2.3	A	V _{IN} = 10V, V _{DS} > 5V
Dynamic Characteristics						
Turn-On Time (V _{IN} to 90% I _D)	t _{ON}	—	3	—	μs	R _L = 22Ω, V _{IN} = 0V to 10V V _{DD} = 12V
Turn-Off Time (V _{IN} to 90% I _D)	t _{OFF}	—	13	—	μs	R _L = 22Ω, V _{IN} = 10V to 0V V _{DD} = 12V
Slew Rate On (70% to 50% V _{DD})	-dV _{DS} /dt _{ON}	—	8	—	V/μs	R _L = 22Ω, V _{IN} = 0V to 10V V _{DD} = 12V
Slew Rate Off (50% to 70% V _{DD})	dV _{DS} /dt _{ON}	—	3.2	—	V/μs	R _L = 22Ω, V _{IN} = 10V to 0V V _{DD} = 12V
Protection Functions (Note 10)						
Minimum Input Voltage for Overtemperature Protection	V _{PROT}	4.5	—	—	V	—
Thermal Overload Trip Temperature	T _{JT}	+150	+175	—	°C	—
Thermal Hysteresis	—	—	+1	—	°C	—
Unclamped Single Pulse Inductive Energy T _J = +25°C	E _{AS}	550	—	—	mJ	I _{D(ISO)} = 0.7A, V _{DD} = 32V
Unclamped Single Pulse Inductive Energy T _J = +150°C	E _{AS}	200	—	—	mJ	I _{D(ISO)} = 0.7A, V _{DD} = 32V
Inverse Diode						
Source-Drain Voltage	V _{SD}	—	—	1	V	V _{IN} = 0V, -I _D = 1.4A

Notes: 8. Protection features may operate outside spec for V_{IN} < 4.5V.

9. The drain current is limited to a reduced value when V_{DS} exceeds a safe level.

10. Integrated protection functions are designed to prevent IC destruction under fault conditions described in the datasheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous, repetitive operation.



BSP75NQ

Application Information

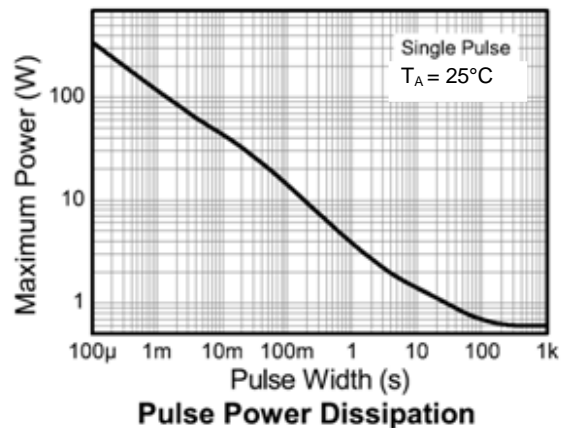
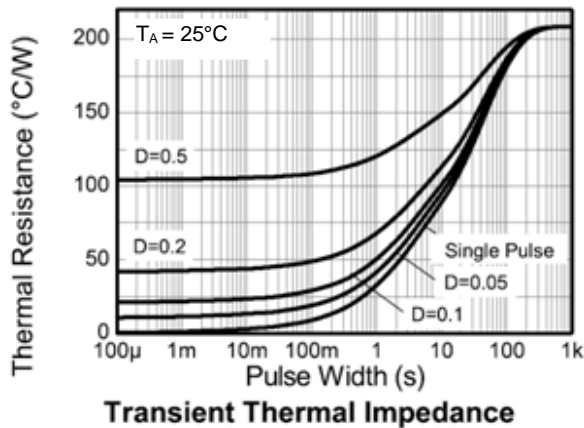
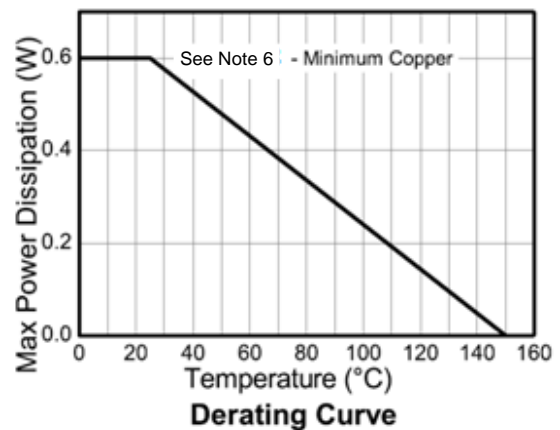
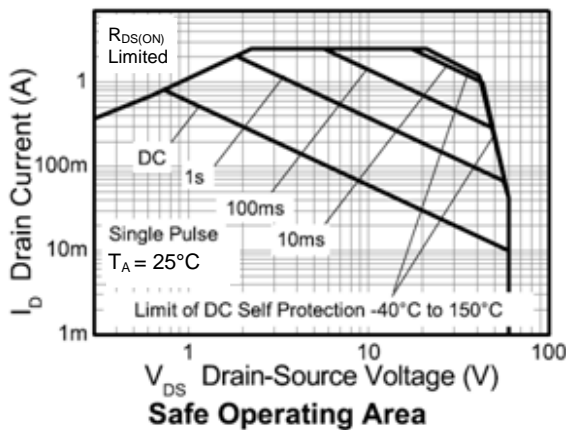
The current-limit protection circuitry is designed to de-activate at low V_{DS} to prevent the load current from being unnecessarily restricted during normal operation. The design max DC operating current is therefore determined by the thermal capability of the package/board combination, rather than by the protection circuitry (see *Typical Characteristics* graphs). This does not compromise the products ability to self-protect at low V_{DS} .

The overtemperature protection circuit trips at a minimum of +150°C. So the available package dissipation reduces as the maximum required ambient temperature increases. This leads to the following maximum recommended continuous operating currents.

Minimum Copper Area Characteristics

For minimum copper condition as described in Note 6.

Max Ambient Temperature T_A	Maximum Continuous Current	
	$V_{IN} = 5V$	$V_{IN} = 10V$
+25°C at $V_{IN} = 5V$	720mA	840mA
+70°C at $V_{IN} = 5V$	575mA	670mA
+85°C at $V_{IN} = 5V$	520mA	605mA
+125°C at $V_{IN} = 5V$	320mA	375mA



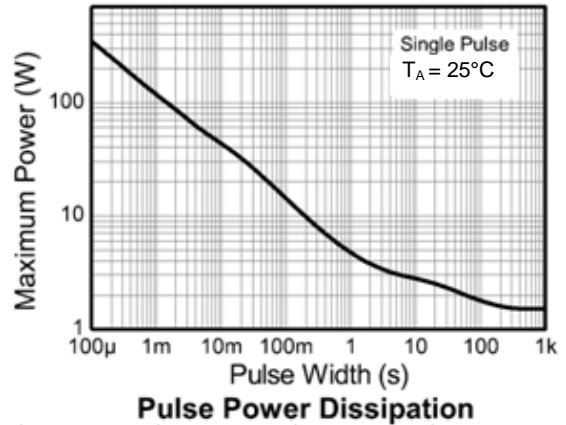
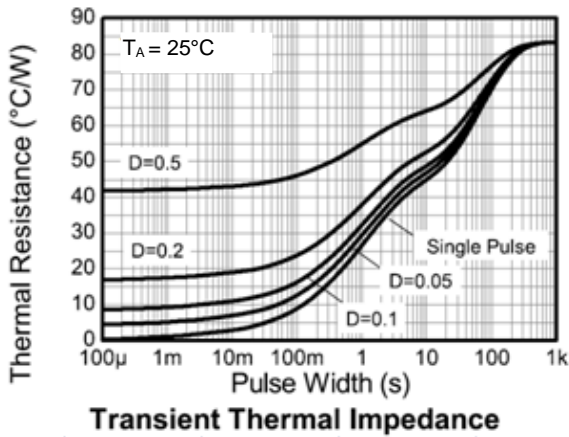
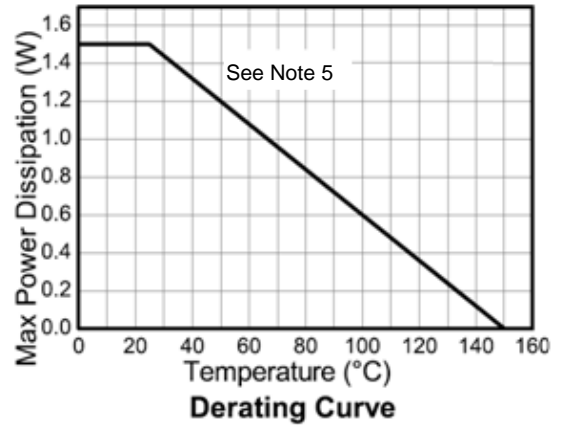
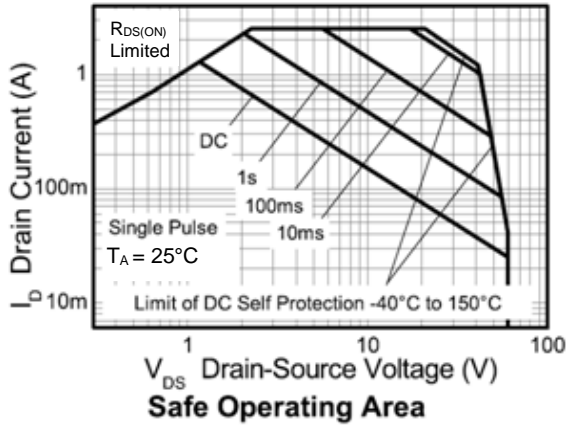


BSP75NQ

Large Copper Area Characteristics

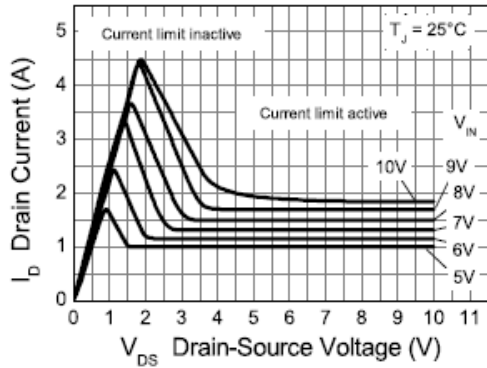
For large copper area as described in Note 5.

Max Ambient Temperature T_A	Maximum Continuous Current	
	$V_{IN} = 5V$	$V_{IN} = 10V$
+25°C at $V_{IN} = 5V$	1140mA	1325mA
+70°C at $V_{IN} = 5V$	915mA	1060mA
+85°C at $V_{IN} = 5V$	825mA	955mA
+125°C at $V_{IN} = 5V$	510mA	590mA

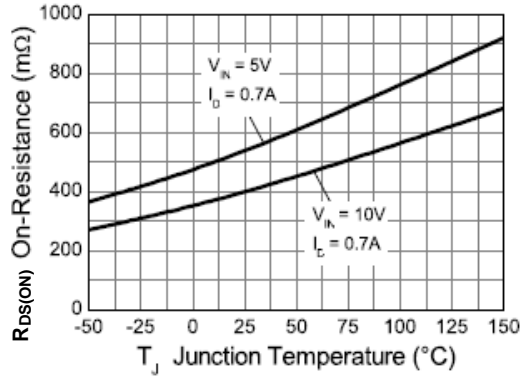




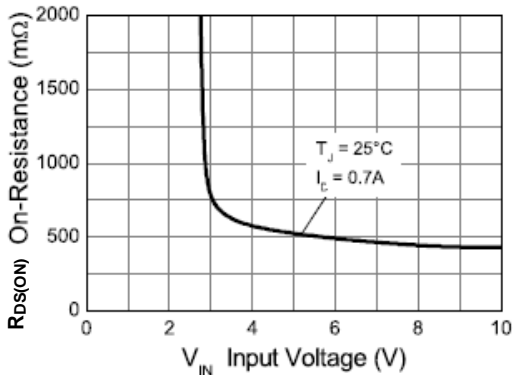
Typical Characteristics



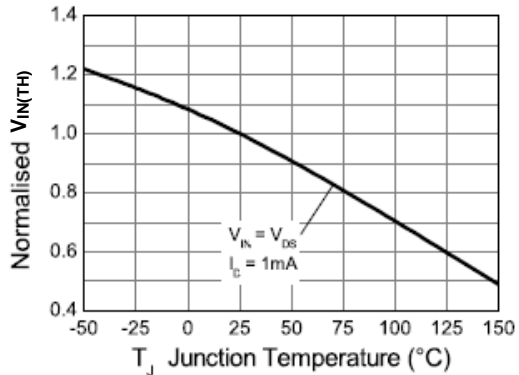
Typical Output Characteristic



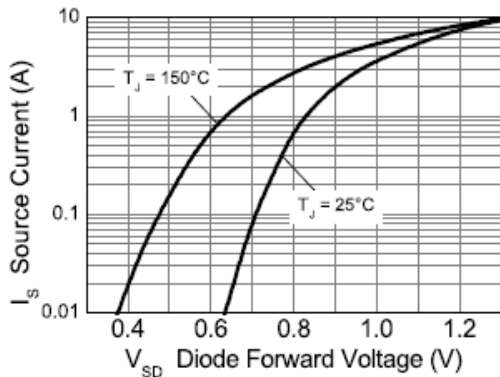
On-State Resistance vs Temperature



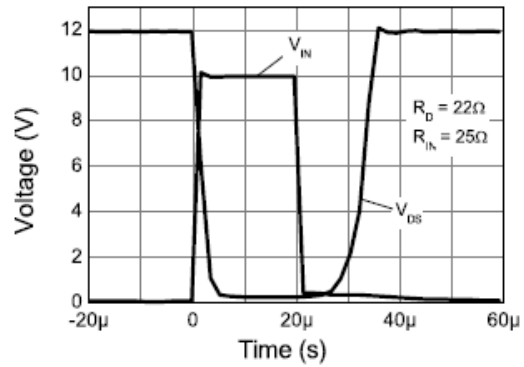
On-Resistance vs Input Voltage



Threshold Voltage vs Temperature



Source-Drain Diode Forward Voltage

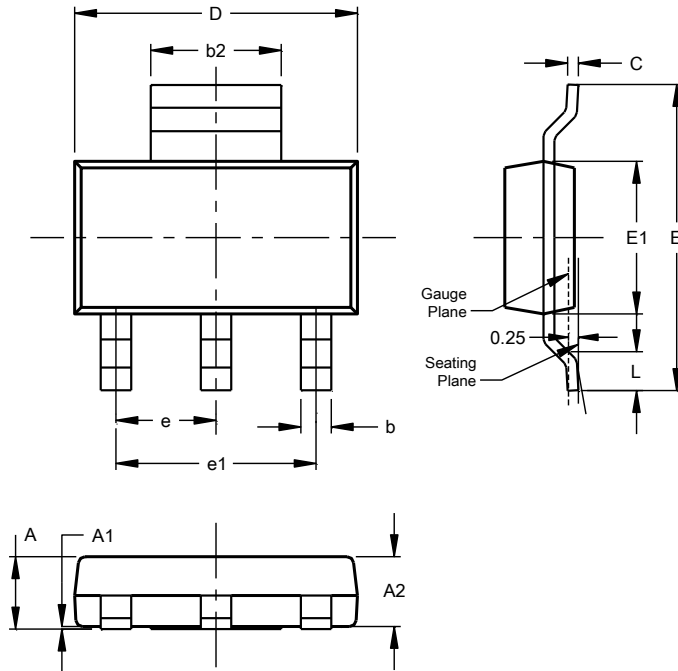


Switching Speed

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)

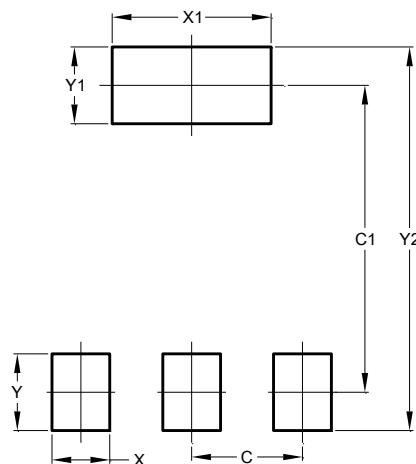


SOT223 (Type DN)			
Dim	Min	Max	Typ
A	--	1.70	--
A1	0.01	0.15	--
A2	1.50	1.68	1.60
b	0.60	0.80	0.70
b2	2.90	3.10	--
c	0.20	0.32	--
D	6.30	6.70	--
E	6.70	7.30	--
E1	3.30	3.70	--
e	--	--	2.30
e1	--	--	4.60
L	0.85	--	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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